

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

DESCRIPTION

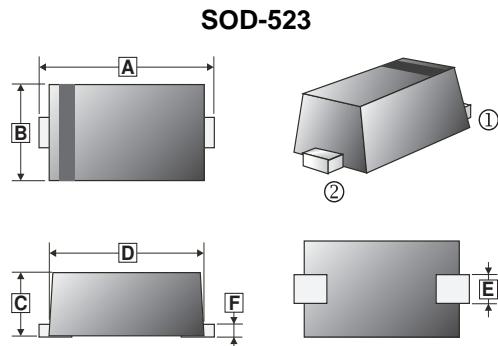
- Ultra Small Plastic SMD Package
- High Continuous Reverse Voltage
- High Switching Speed
- Band Indicates Cathode

MARKING

L4

PACKAGE INFORMATION

Package	MPQ	Leader Size
SOD-523	3K	7 inch



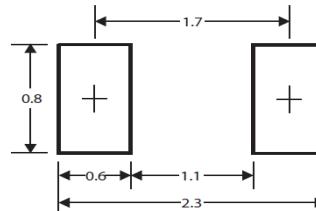
REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	1.50	1.70	D	1.10	1.30
B	0.70	0.90	E	0.25	0.40
C	0.50	0.77	F	-	0.20

ORDER INFORMATION

Part Number	Type
BAS521-C	Lead (Pb)-free and Halogen-free



Mounting Pad Layout



*Dimensions in millimeters

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating		Unit
Repetitive Peak Reverse Voltage	V_{RRM}	300		V
Continuous Reverse Voltage	V_R	300		V
Continuous Forward Current $T_S \leq 90^\circ\text{C}$	I_F	250		mA
Repetitive Peak Forward Current @ $t_p=1\text{ms}$	I_{FRM}	1		A
Non-Repetitive Peak Forward Surge Current @ $t_p=1\text{ms}$, square wave	$T_J=25^\circ\text{C}$	I_{FSM}	4.5	A
Power Dissipation	$T_S \leq 90^\circ\text{C}$	P_D	500	mW
Operating Junction & Storage Temperature Range	T_J, T_{STG}	150, -65~150		°C

Note:

1. T_S is the temperature at the soldering point of the cathode tab.

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Breakdown Voltage	V_{BR}	300	340	-	V	$I_R=100\mu\text{A}$
Forward Voltage	V_F	-	0.95	1.1	V	$I_F=100\text{mA}$
Reverse Leakage Current	I_R	-	30	150	μA	$V_R=250\text{V}$
		-	40	100		$V_R=250\text{V}, T_J=150^\circ\text{C}$
Diode Capacitance	C_D	-	0.4		pF	$V_R=0\text{V}, f=1\text{MHz}$
Reverse Recovery Time	T_{RR}	-	16	-	nS	$I_F=I_R=30\text{mA}, I_{RR}=3\text{mA}, R_L=100\Omega$

RATINGS AND CHARACTERISTIC CURVES

Fig 1 Forward current as a function of forward voltage; typical values.

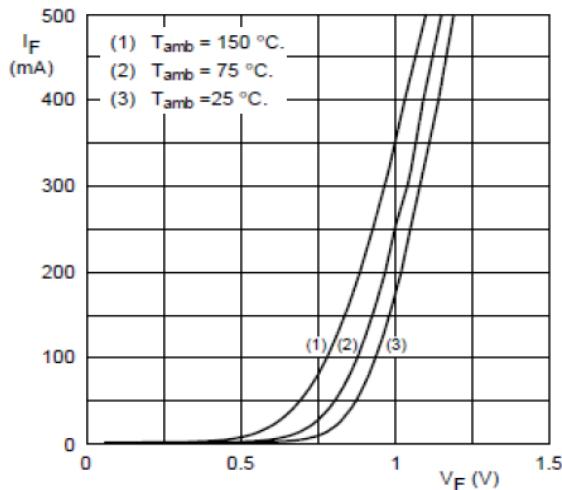


Fig 2 Reverse current as a function of junction temperature.

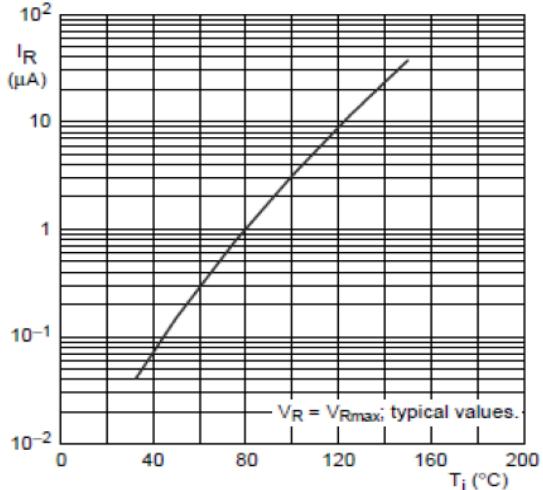


Fig 3 Maximum permissible continuous forward current as a function of ambient temperature.

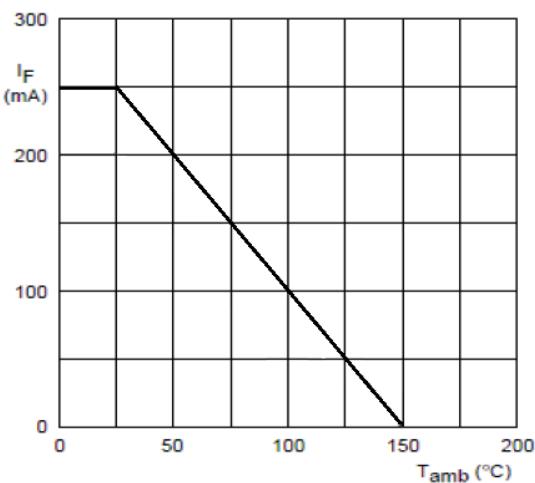


Fig 4 Diode capacitance as a function of reverse voltage; typical values.

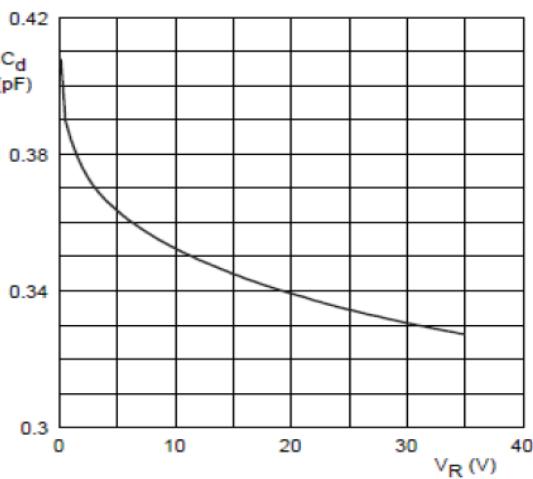


Fig 5 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

